NCE N-Channel Super Trench Power MOSFET

Description

The NCEP15T14 uses **Super Trench** technology that is uniquely optimized to provide the most efficient high frequency switching performance. Both conduction and switching power losses are minimized due to an extremely low combination of $R_{DS(ON)}$ and Q_g . This device is ideal for high-frequency switching and synchronous rectification.

General Features

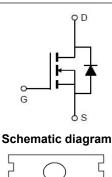
- V_{DS} =150V, I_D =140A $R_{DS(ON)}$ =5.8m Ω , typical @ V_{GS} =10V
- Excellent gate charge x R_{DS(on)} product(FOM)
- Very low on-resistance R_{DS(on)}
- 175 °C operating temperature
- Pb-free lead plating
- 100% UIS tested

Application

- DC/DC Converter
- Ideal for high-frequency switching and synchronous rectification

100% UIS TESTED!

100% AVds TESTED!





Marking and pin assignment



TO-220-3L top view

Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCEP15T14	NCEP15T14	TO-220-3L	-	-	-

Absolute Maximum Ratings (T_C=25℃unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V _{DS}	150	V
Gate-Source Voltage	Vgs	±20	V
Drain Current-Continuous	I _D	140	Α
Drain Current-Continuous(T _C =100 °C)	I _D (100°C)	100	А
Pulsed Drain Current	I _{DM}	560	А
Maximum Power Dissipation	P _D	320	W
Derating factor		2.1	W/℃
Single pulse avalanche energy (Note 1)	Eas	1296	mJ
Operating Junction and Storage Temperature Range	T _J ,T _{STG}	-55 To 175	°C

Thermal Characteristic

Thermal Resistance,Junction-to-Case	R _{θJC}	0.47	°C/W
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Electrical Characteristics (T_C=25°C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =250µA	150	-	-	V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =150V,V _{GS} =0V	-	-	1	μA
Gate-Body Leakage Current	I _{GSS}	V _{GS} =±20V,V _{DS} =0V	-	-	±100	nA
On Characteristics						
Gate Threshold Voltage	V _{GS(th)}	$V_{DS}=V_{GS},I_{D}=250\mu A$	2.0	3.0	4.0	V
Drain-Source On-State Resistance	R _{DS(ON)}	V _{GS} =10V, I _D =70A	-	5.8	6.5	mΩ
Forward Transconductance	g FS	V _{DS} =10V,I _D =70A	70	-	-	S
Dynamic Characteristics			•			
Input Capacitance	C _{lss}	\/ 75\/\\ 0\/	-	6000	-	PF
Output Capacitance	Coss	V_{DS} =75 V , V_{GS} =0 V ,	-	690	-	PF
Reverse Transfer Capacitance	C _{rss}	F=1.0MHz	-	24	-	PF
Switching Characteristics (Note 2)						
Turn-on Delay Time	t _{d(on)}		-	26	-	nS
Turn-on Rise Time	t _r	V_{DD} =75 V , I_D =70 A	-	36	-	nS
Turn-Off Delay Time	t _{d(off)}	$V_{GS}\text{=}10V, R_{G}\text{=}4.7\Omega$	-	47	-	nS
Turn-Off Fall Time	t _f		-	15	-	nS
Total Gate Charge	Qg)/ 75\/\ 70A	-	80	-	nC
Gate-Source Charge	Q _{gs}	$V_{DS}=75V, I_{D}=70A,$	-	32	-	nC
Gate-Drain Charge	Q _{gd}	V _{GS} =10V	-	22	-	nC
Drain-Source Diode Characteristics			•			•
Diode Forward Voltage	V _{SD}	V _{GS} =0V,I _F = I _S	-		1.2	V
Diode Forward Current	Is		-	-	140	Α
Reverse Recovery Time	t _{rr}	T _J = 25°C, I _F = I _S	-	146		nS
Reverse Recovery Charge	Qrr	di/dt = 100A/µs	-	485		nC

Notes:

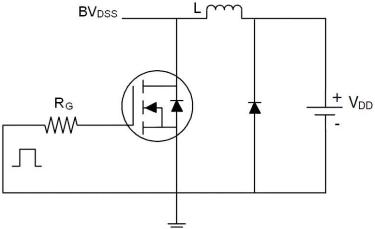
^{1.} EAS condition : Tj=25 $^{\circ}\text{C}$,VDD=50V,VG=10V,L=0.5mH,Rg=25 Ω

^{2.} Guaranteed by design, not subject to production

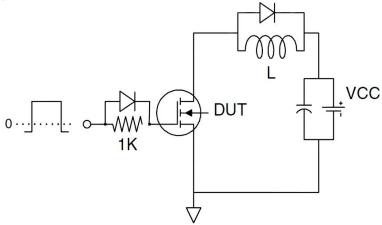
^{3.} These curves are based on the junction-to-case thermal impedance which is measured with the device mounted to a large heatsin k, assuming a maximum junction temperature of TJ(MAX)=175° C. The SOA curve provides a single pulse rating.

Test Circuit

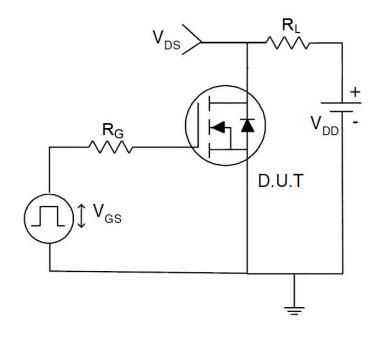
1) E_{AS} test Circuit



2) Gate charge test Circuit



3) Switch Time Test Circuit



Typical Electrical and Thermal Characteristics

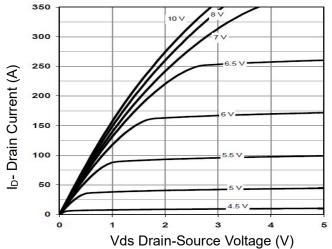


Figure 1 Output Characteristics

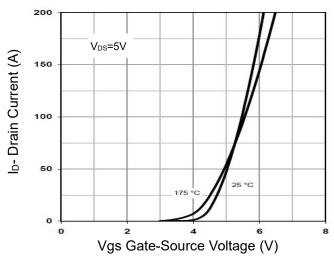


Figure 2 Transfer Characteristics

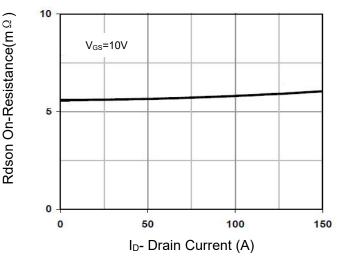


Figure 3 Rdson- Drain Current

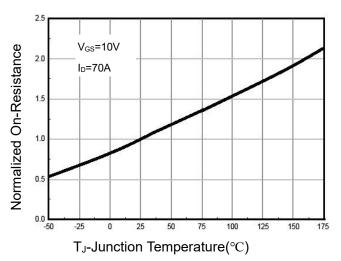


Figure 4 Rdson-JunctionTemperature

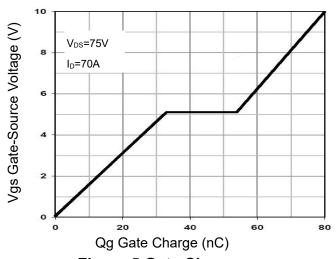


Figure 5 Gate Charge

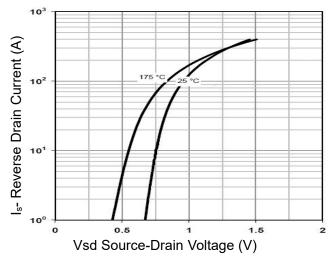
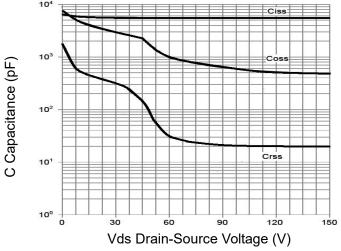


Figure 6 Source- Drain Diode Forward





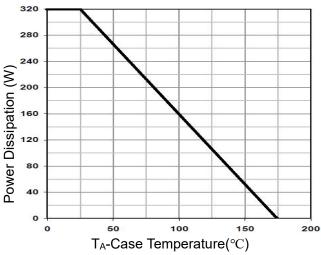
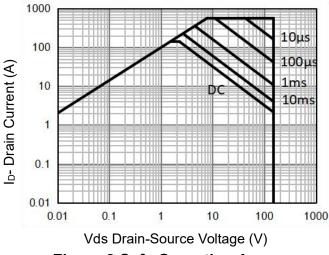


Figure 7 Capacitance vs Vds

Figure 9 Power De-rating



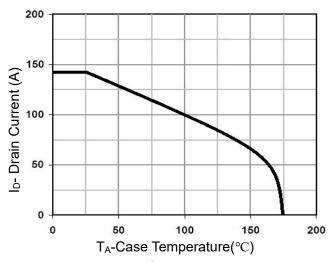


Figure 8 Safe Operation Area(Note3)

Figure 10 Current De-rating

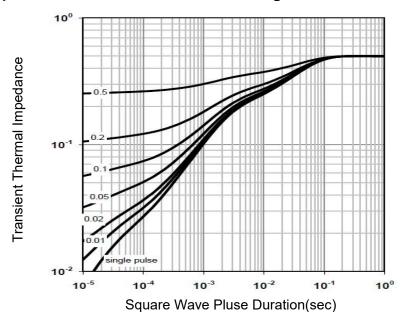
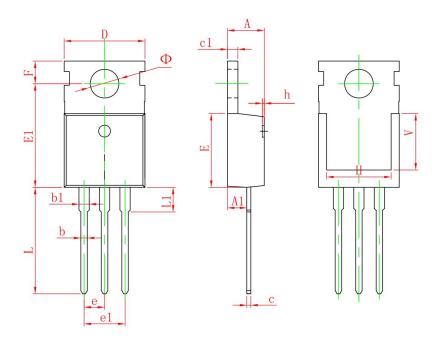


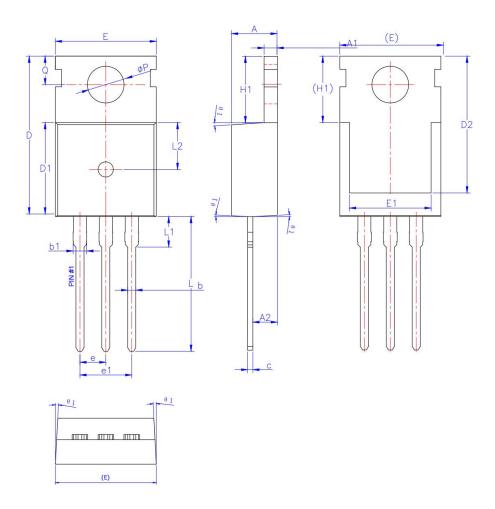
Figure 11 Normalized Maximum Transient Thermal Impedance

TO-220-3L(C) Package Information



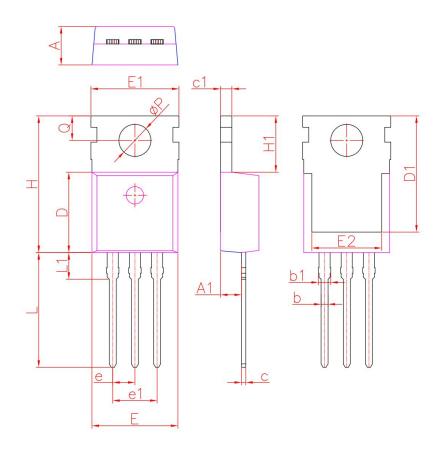
Symbol	Dimensions	In Millimeters	Dimensions In Inches		
Symbol	Min.	Max.	Min.	Max.	
Α	4.400	4.600	0.173	0.181	
A1	2.250	2.550	0.089	0.100	
b	0.710	0.910	0.028	0.036	
b1	1.170	1.370	0.046	0.054	
С	0.330	0.650	0.013	0.026	
c1	1.200	1.400	0.047	0.055	
D	9.910	10.250	0.390	0.404	
E	8.950	9.750	0.352	0.384	
E1	12.650	13.050	0.498	0.514	
е	2.540	TYP.	0.100 TYP.		
e1	4.980	5.180	0.196	0.204	
F	2.650	2.950	0.104	0.116	
Н	7.900	8.100	0.311	0.319	
h	0.000	0.300	0.000	0.012	
L	12.900	13.400	0.508	0.528	
L1	2.850	3.250	0.112	0.128	
V	6.900 REF.		0.276 REF.		
Φ	3.400	3.800	0.134	0.150	

TO-220-3L(P) Package Information



SYMBOL MIN NOM MAX A 4.40 4.50 4.60 A1 1.27 1.30 1.33 A2 2.30 2.40 2.50 b 0.70 — 0.90 b1 — — 1.40 c 0.45 0.50 0.60 D 15.30 15.70 16.10 D1 9.10 9.20 9.30 D2 13.10 — 13.70 E 9.70 9.90 10.20 E1 7.80 8.00 8.20 e 2.54BSC e1 5.08BSC H1 6.30 6.50 6.70 L 12.78 13.08 13.38 L1 — — 3.50 L2 4.60REF ØP 3.55 3.60 3.65 Q 2.73 — 2.87 θ1 1* 3* 5* </th <th></th> <th></th> <th></th> <th></th>					
A1 1.27 1.30 1.33 A2 2.30 2.40 2.50 b 0.70 - 0.90 b1 - - 1.40 c 0.45 0.50 0.60 D 15.30 15.70 16.10 D1 9.10 9.20 9.30 D2 13.10 - 13.70 E 9.70 9.90 10.20 E1 7.80 8.00 8.20 e 2.54BSC e1 5.08BSC H1 6.30 6.50 6.70 L 12.78 13.08 13.38 L1 - - 3.50 L2 4.60REF Q 2.73 - 2.87	SYMBOL	MIN	NOM	MAX	
A2 2.30 2.40 2.50 b 0.70 - 0.90 b1 - - 1.40 c 0.45 0.50 0.60 D 15.30 15.70 16.10 D1 9.10 9.20 9.30 D2 13.10 - 13.70 E 9.70 9.90 10.20 E1 7.80 8.00 8.20 e 2.54BSC e1 5.08BSC H1 6.30 6.50 6.70 L 12.78 13.08 13.38 L1 - - 3.50 L2 4.60REF ØP 3.55 3.60 3.65 Q 2.73 - 2.87	A	4.40	4.50	4.60	
b 0.70 - 0.90 b1 - - 1.40 c 0.45 0.50 0.60 D 15.30 15.70 16.10 D1 9.10 9.20 9.30 D2 13.10 - 13.70 E 9.70 9.90 10.20 E1 7.80 8.00 8.20 e 2.54BSC e1 5.08BSC H1 6.30 6.50 6.70 L 12.78 13.08 13.38 L1 - - 3.50 L2 4.60REF ØP 3.55 3.60 3.65 Q 2.73 - 2.87	A1	1.27	1.30	1.33	
b1	A2	2.30	2.40	2.50	
c 0.45 0.50 0.60 D 15.30 15.70 16.10 D1 9.10 9.20 9.30 D2 13.10 — 13.70 E 9.70 9.90 10.20 E1 7.80 8.00 8.20 e 2.54BSC e1 5.08BSC H1 6.30 6.50 6.70 L 12.78 13.08 13.38 L1 — — 3.50 L2 4.60REF ØP 3.55 3.60 3.65 Q 2.73 — 2.87	b	0.70	_	0.90	
D 15.30 15.70 16.10 D1 9.10 9.20 9.30 D2 13.10 — 13.70 E 9.70 9.90 10.20 E1 7.80 8.00 8.20 e 2.54BSC e1 5.08BSC H1 6.30 6.50 6.70 L 12.78 13.08 13.38 L1 — 3.50 L2 4.60REF ØP 3.55 3.60 3.65 Q 2.73 — 2.87	b1	_	_	1.40	
D1 9.10 9.20 9.30 D2 13.10 — 13.70 E 9.70 9.90 10.20 E1 7.80 8.00 8.20 e 2.54BSC e1 5.08BSC H1 6.30 6.50 6.70 L 12.78 13.08 13.38 L1 — 3.50 L2 4.60REF ØP 3.55 3.60 3.65 Q 2.73 — 2.87	С	0.45	0.50	0.60	
D2 13.10 — 13.70 E 9.70 9.90 10.20 E1 7.80 8.00 8.20 e 2.54BSC e1 5.08BSC H1 6.30 6.50 6.70 L 12.78 13.08 13.38 L1 — 3.50 L2 4.60REF ØP 3.55 3.60 3.65 Q 2.73 — 2.87	D	15.30	15.70	16.10	
E 9.70 9.90 10.20 E1 7.80 8.00 8.20 e 2.54BSC e1 5.08BSC H1 6.30 6.50 6.70 L 12.78 13.08 13.38 L1 3.50 L2 4.60REF ØP 3.55 3.60 3.65 Q 2.73 - 2.87	D1	9.10	9.20	9.30	
E1 7.80 8.00 8.20 e 2.54BSC e1 5.08BSC H1 6.30 6.50 6.70 L 12.78 13.08 13.38 L1 3.50 L2 4.60REF ØP 3.55 3.60 3.65 Q 2.73 - 2.87	D2	13.10	_	13.70	
e 2.54BSC e1 5.08BSC H1 6.30 6.50 6.70 L 12.78 13.08 13.38 L1 3.50 L2 4.60REF ØP 3.55 3.60 3.65 Q 2.73 - 2.87	E	9.70	9.90	10.20	
e1 5.08BSC H1 6.30 6.50 6.70 L 12.78 13.08 13.38 L1 3.50 L2 4.60REF ØP 3.55 3.60 3.65 Q 2.73 - 2.87	E1	7.80	8.00	8.20	
H1 6.30 6.50 6.70 L 12.78 13.08 13.38 L1 3.50 L2 4.60REF ØP 3.55 3.60 3.65 Q 2.73 - 2.87	е	2	2.54BSC		
L 12.78 13.08 13.38 L1 – – 3.50 L2 4.60REF ØP 3.55 3.60 3.65 Q 2.73 – 2.87	e1	5.08BSC			
L1 – – 3.50 L2 4.60REF ØP 3.55 3.60 3.65 Q 2.73 – 2.87	H1	6.30	6.50	6.70	
L2 4.60REF ØP 3.55 3.60 3.65 Q 2.73 – 2.87	L	12.78	13.08	13.38	
ØP 3.55 3.60 3.65 Q 2.73 - 2.87	L1	= 1	-	3.50	
Q 2.73 – 2.87	L2	4.60REF			
NAME OF TAXABLE PARTY O	ØΡ	3.55	3.60	3.65	
θ1 1* 3* 5*	Q	2.73	_	2.87	
	θ 1	1*	3°	5*	

TO-220-3L(E) Package Information



TO220					
DIM.	MIN.	NOM.	MAX.		
A	4.20	4.40	4.60		
A1	2.25	2.40	2.55		
b	0.70	0.80	0.90		
b1	1.17	1.27	1.37		
С	0.33	0.50	0.65		
c1	1.20	1.30	1.40		
D	8.95	9.20	9.75		
D1	13.10	13.30	13.50		
E	9.74	9.84	10.04		
E1	9.91	10.08	10.25		
E2	7.90	8.00	8.10		
е		2.54BSC			
e1		5.08BSC			
Н	15.45	15.65	15.85		
H1	6.30	6.45	6.60		
L.	12.90	13.13	13.40		
L1	2.85	3.05	3.25		
Q	2.65	2.80	2.95		
ØΡ	3.40	3.68	3.80		
All	All dimensions in millimeters				

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